# NSN 5961-00-138-7164

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Inclosure Material:

Metal

**Overall Length:** 

0.340 inches

## **Overall Diameter:**

0.500 inches

# **Mounting Facility Quantity:**

2

#### Internal Configuration:

Junction contact

## Electrode Internally-electrically Connected To Case:

Collector

#### **Mounting Method:**

Unthreaded hole

Features Provided:

#### Hermetically sealed case

Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

500.0 breakdown voltage, collector-to-base, emitter open and 300.0 breakdown voltage, collector-to-emitter, base open and 6.0

breakdown voltage, emitter-to-base, collector open

#### **Current Rating Per Characteristic:**

2.00 amperes source cutoff current

## Power Rating Per Characteristic:

35.0 watts small-signal input power, common-collector preset

## Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

#### **Special Features:**

Junction pattern arrangement: npn

#### Test Data Document:

15786-84398 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

## **Terminal Type And Quantity:**

2 pin and 1 case Shelf Life: N/a Unit Of Measure: --Demilitarization: No Fiig:

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